Exam.Code:0970 Sub. Code: 7347

1129

M.E. (Electronics and Communication Engineering)

Second Semester ECE-1205: VLSI Design

Time allowed: 3 Hours

Max. Marks: 50

NOTE: Attempt five questions in all, including question No. I which is compulsory and selecting

X-X-X

- Attempt the following:-I.
 - a) What is a pass transistor? What are its applications? Compare it with a transmission
 - b) List four CAD tools used in VLSI design.
 - c) Differentiate between placement and routing in VLSI layout.
 - d) Differentiate between an RS flip flop and a toggle flip flop.
 - e) What are ratioed circuits? What are their applications?

(5x2)

UNIT - I

- In an NMOSFET, explain the weak, moderate and strong inversion regions. Explain the II. linear and saturation regions of IV characteristics of a p type MOSFET.
- Differentiate between a CMOS inverter and a MOS inverter with active load. What is an III. active resistor? Draw transfer characteristics of a CMOS inverter.
- Explain the working of NOR and NAND logic gates using a MOSFET. Also explain the IV. design steps of such logic gates. Compare these gates with the Bi-CMOS NOR and NAND gates. (10)

UNIT – II

- Explain how a VLSI digital circuit can be described using a language? Explain the salient V. features and types of such a language. (10)
- Explain and compare the terms placement and floor planning. What are their types? VI. Name two of the algorithms of placement and floor planning. (10)
- VII. Write notes on:
 - a) Power line distribution in a VLSI layout
 - b) Types of routing in a VLSI layout.

(5,5)